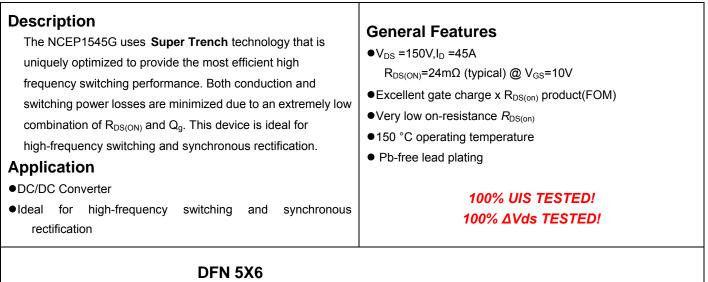
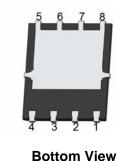


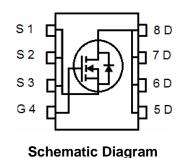
NCE N-Channel Super Trench Power MOSFET











Package Marking and Ordering Information

U	0	<u> </u>			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P1545G	NCEP1545G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	150	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	Ι _D	45	А
Drain Current-Continuous(T _C =100 °C)	l _D (100℃)	31.8	A
Pulsed Drain Current	I _{DM}	180	A
Maximum Power Dissipation	PD	110	W
Derating factor		0.88	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	200	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Résistance, Junction-to-Case ^(Note 2)	R _{θJC}	1.14	°C/W
	1,610		0/11



Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	· ·		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	150	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±20V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.1	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V_{GS} =10V, I _D =20A	-	24	28	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =20A	15	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	V _{DS} =75V,V _{GS} =0V,	-	1300		PF
Output Capacitance	C _{oss}		-	162		PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	11.7		PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	tr	V_{DD} =75V, RL=7.5 Ω	-	6.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_G =3 Ω	-	16	-	nS
Turn-Off Fall Time	t _f		-	7	-	nS
Total Gate Charge	Qg	\/ _75\/ _20A	-	21.1	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS} = 75V, I_D = 20A,$	-	8	-	nC
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	4.6	-	nC
Drain-Source Diode Characteristics	· ·		•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current (Note 2)	I _S		-	-	45	А
Reverse Recovery Time	t _{rr}	T_J = 25°C, I_F = I_S	-	30	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs ^(Note3)	-	135	-	nC

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

2. Surface Mounted on FR4 Board, $t \le 10$ sec.

3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.

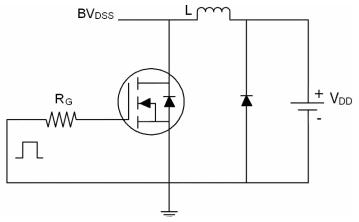
4. Guaranteed by design, not subject to production

5. EAS condition : Tj=25 $^\circ \!\! C$,V_DD=75V,V_G=10V,L=0.5mH,Rg=25\Omega

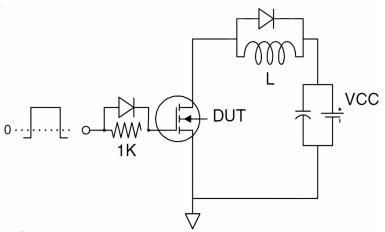


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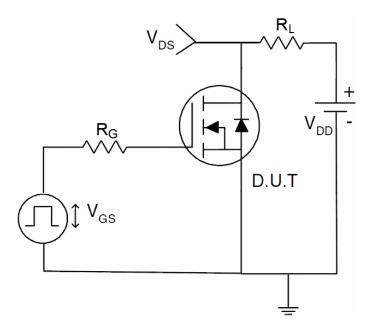
Test Circuit 1) E_{AS} test Circuit



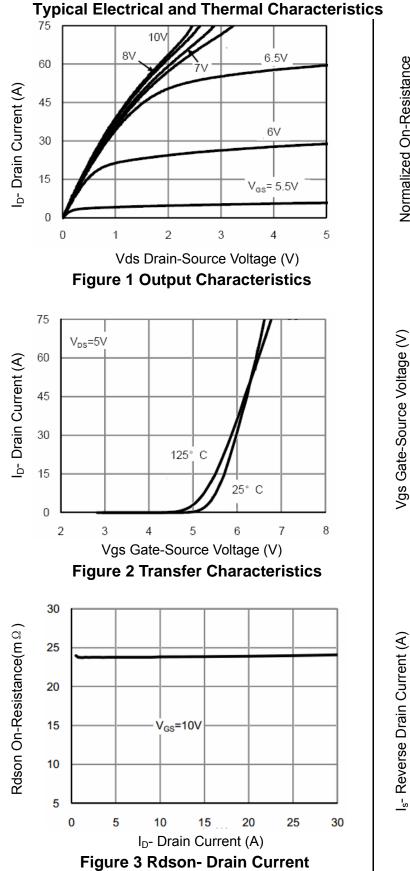
2) Gate charge test Circuit

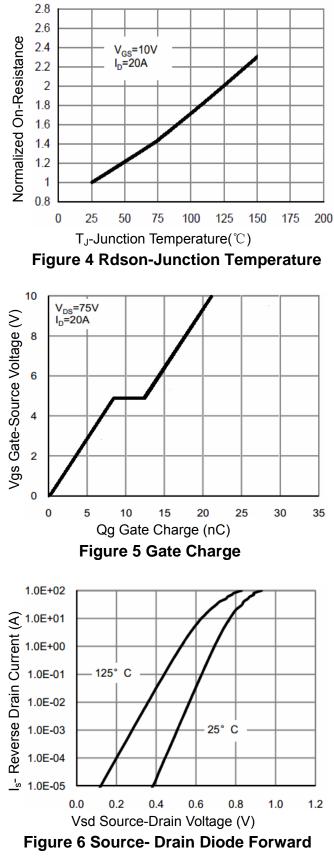


3) Switch Time Test Circuit











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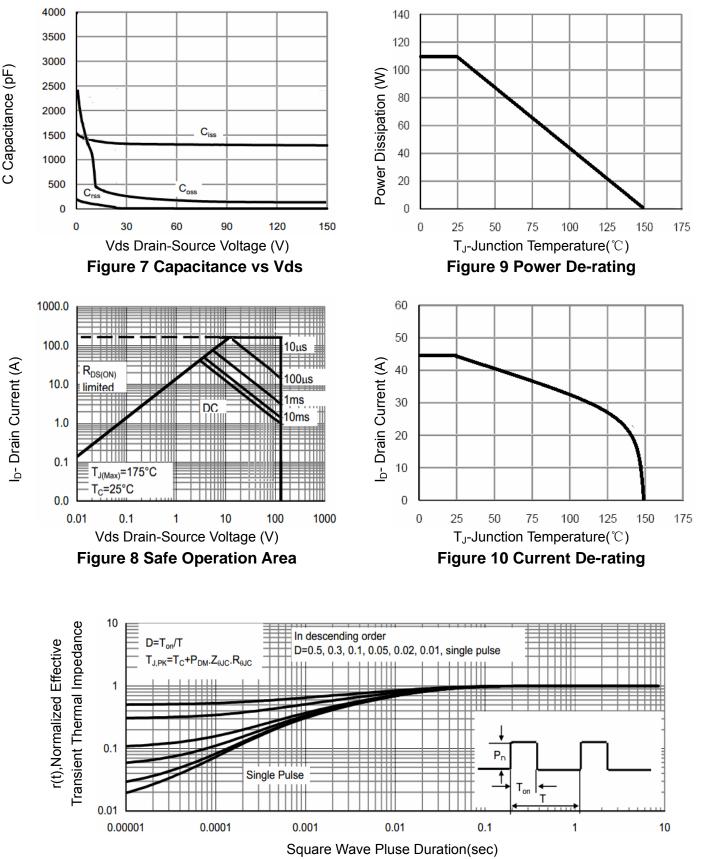
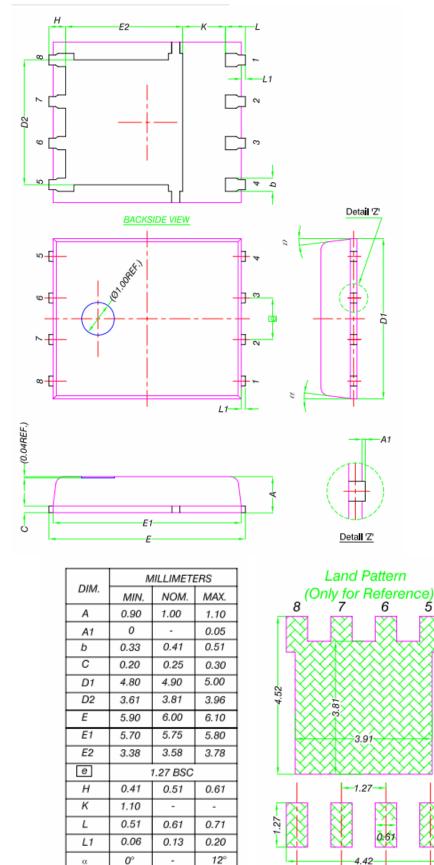


Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information



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